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**Operating Tempurature Range:** 

+0.0/+70.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

## End Application:

TEST-PR-OGR-AMSE

## **Features Provided:**

High speed and low power and asynchronous and high performance

## **Inclosure Material:**

Plastic

## Inclosure Configuration:

Dual-in-line

Product Name:

Cmos asynchronous fifo

## Voltage Rating And Type Per Characteristic:

-0.5 volts input and 7.0 volts input

## **Time Rating Per Chacteristic:**

35.00 nanoseconds af output megawatts

### Memory Device Type:

First-in first-out

## **Special Features:**

4096 x 9

## **Terminal Type And Quantity:**

28 printed circuit

## Shelf Life:

N/a

#### Unit Of Measure:

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# Demilitarization:

Yes - demil/mli

Fiig:

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